

PRODUCT STANDARDS

PART No. :	AN4801SB
PACKAGE CODE No.	HSOP042-P-0400B

IC DIVISION  
SEMICONDUCTOR COMPANY  
MATSUSHITA ELECTRONICS CORPORATION

-----	CHECKED BY	CHECKED BY	PREPARED BY
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DATE PREPARED				
Nov. 2, 2000				

Type	Silicon Monolithic Bipolar IC
Package	DIL 26-Pin Plastic Package ( USOF Type )
Application	Driver for CD/MD
Function	4-channel Power OP Amp System Driver

A	Absolute Maximum Ratings				
No.	Parameter	Symbol	Rating	Unit	Note
1	Storage temperature	Tstg	-55 to +150	℃	1
2	Operating ambient temperature	Topr	-30 to +85	℃	1
3	Operating ambient atmospheric pressure	Popr	$1.013 \times 10^5 \pm 0.61 \times 10^5$	Pa	
4	Operating constant gravity	Gopr	9810	m/s <sup>2</sup>	
5	Operating shock	Sopr	4900	m/s <sup>2</sup>	
6	Supply voltage	SVcc PVcc1, 2	14	V	
7	Supply current	ISVcc IPVcc1 IPVcc2	0.1 1.3 1.3	A	2
8	Supply voltage applicable range	SVcc PVcc1, 2	-0.3 to 14.0	V	
9	Power dissipation	PD	537	mW	3

Operating supply voltage range	<table style="width: 100%; border-collapse: collapse;"> <tr> <td style="width: 15%; padding: 2px;">SVcc</td> <td style="padding: 2px;">4.5 V to 13.5 V</td> </tr> <tr> <td style="padding: 2px;">PVcc1</td> <td style="padding: 2px;">3.0 V to 13.5 V</td> </tr> <tr> <td style="padding: 2px;">PVcc2</td> <td style="padding: 2px;">3.0 V to 13.5 V</td> </tr> </table>	SVcc	4.5 V to 13.5 V	PVcc1	3.0 V to 13.5 V	PVcc2	3.0 V to 13.5 V	<div style="border-left: 1px solid black; border-right: 1px solid black; border-bottom: 1px solid black; padding: 5px;">           Operate on condition that PVcc1 and PVcc2 are the same or less than SVcc.         </div>
SVcc	4.5 V to 13.5 V							
PVcc1	3.0 V to 13.5 V							
PVcc2	3.0 V to 13.5 V							

- Note 1) Ta=25℃ except storage temperature and operating ambient temperature.
- Note 2) Make sure that channels 1 to 4 do not have a current flow exceeding 800 mA.
- Note 3) When using this IC, referring to the TECHNICAL DATA (G-1), observe the power dissipation characteristic curve. Be sure to use the IC so that the power dissipation of the IC without heat sink will not exceed 537 mW at Ta=85℃.

A	Absolute Maximum Ratings				
No.	Parameter	Symbol	Rating	Unit	Note
10	Driver output current	$I_o(n)$	$\pm 800$	mA	n=10, 11, 12, 13, 14 15, 16, 17
11	Control signal input voltage	$V_n$	0 to $SV_{CC}$	V	n=1, 2, 3, 4, 20, 24, 25, 26

Note) Do not apply current or voltage from external source to any pin not listed above.

In the circuit current, (+) means the current flowing into IC and (-) means the current flowing out of IC.

B Electrical Characteristics (Ta=25°C ±2°C unless otherwise specified)									
No.	Parameter	Symbol	Test Circuit	Conditions	Limits			Unit	Note
					Min	Typ	Max		
< Current Consumption >									
1	Current consumption at no load	I <sub>tot</sub>	1	V <sub>CC</sub> =8 V V <sub>REF</sub> =V <sub>IN</sub> =1.65 V	-	10	20	mA	
2	Current consumption in standby mode	I <sub>STBY</sub>	1	V <sub>CC</sub> =8 V V <sub>REF</sub> =V <sub>IN</sub> =1.65 V V <sub>STBY</sub> =0 V	-	-	1	mA	
< Motor Driver >									
3	Output offset voltage	V <sub>OFS</sub>	1	V <sub>CC</sub> =8 V V <sub>IN</sub> =V <sub>REF</sub>	-50	0	50	mV	
4	+ Gain	G+	1	V <sub>CC</sub> =8 V V <sub>IN</sub> =V <sub>REF</sub> +0.15 V/0.25 V	13	15	17	dB	
5	Relative gain (+/-)	G	1		-2.0	0	2.0	dB	
6	ch1 & ch4 Max. output amplitude (+)	V <sub>L+</sub>	1	V <sub>IN</sub> =3.3 V	4.9	5.4	-	V	
7	ch1 & ch4 Max. output amplitude (-)	V <sub>L-</sub>	1	V <sub>IN</sub> =0 V	-	-5.4	-4.9	V	
8	ch2 & ch3 Max. output amplitude (+)	V <sub>L+</sub>	1	V <sub>IN</sub> =3.3 V	5.1	5.6	-	V	
9	ch2 & ch3 Max. output amplitude (-)	V <sub>L-</sub>	1	V <sub>IN</sub> =0 V	-	-5.6	-5.1	V	
< Standby Operation >									
10	High-level STBY threshold voltage	V <sub>STBH</sub>	1	V <sub>CC</sub> =8 V	2.2	-	-	V	
11	Low-level STBY threshold voltage	V <sub>STBL</sub>	1	V <sub>CC</sub> =8 V	-	-	0.7	V	
12	Input current in STBY (standby) mode	I <sub>STBY</sub>	1	V <sub>STBY</sub> =3.3 V	-	30	70	μA	
< Reset Circuit >									
13	Reset operation clearing supply voltage	V <sub>RST</sub>	1		-	-	4.3	V	
14	V <sub>REF</sub> detecting voltage	V <sub>R</sub>	1		1.2	-	-	V	

Note) V<sub>CC</sub>=8 V, V<sub>REF</sub>=1.65 V, R<sub>L</sub>=8Ω, and V<sub>STBY</sub>=3.3 V unless otherwise specified.

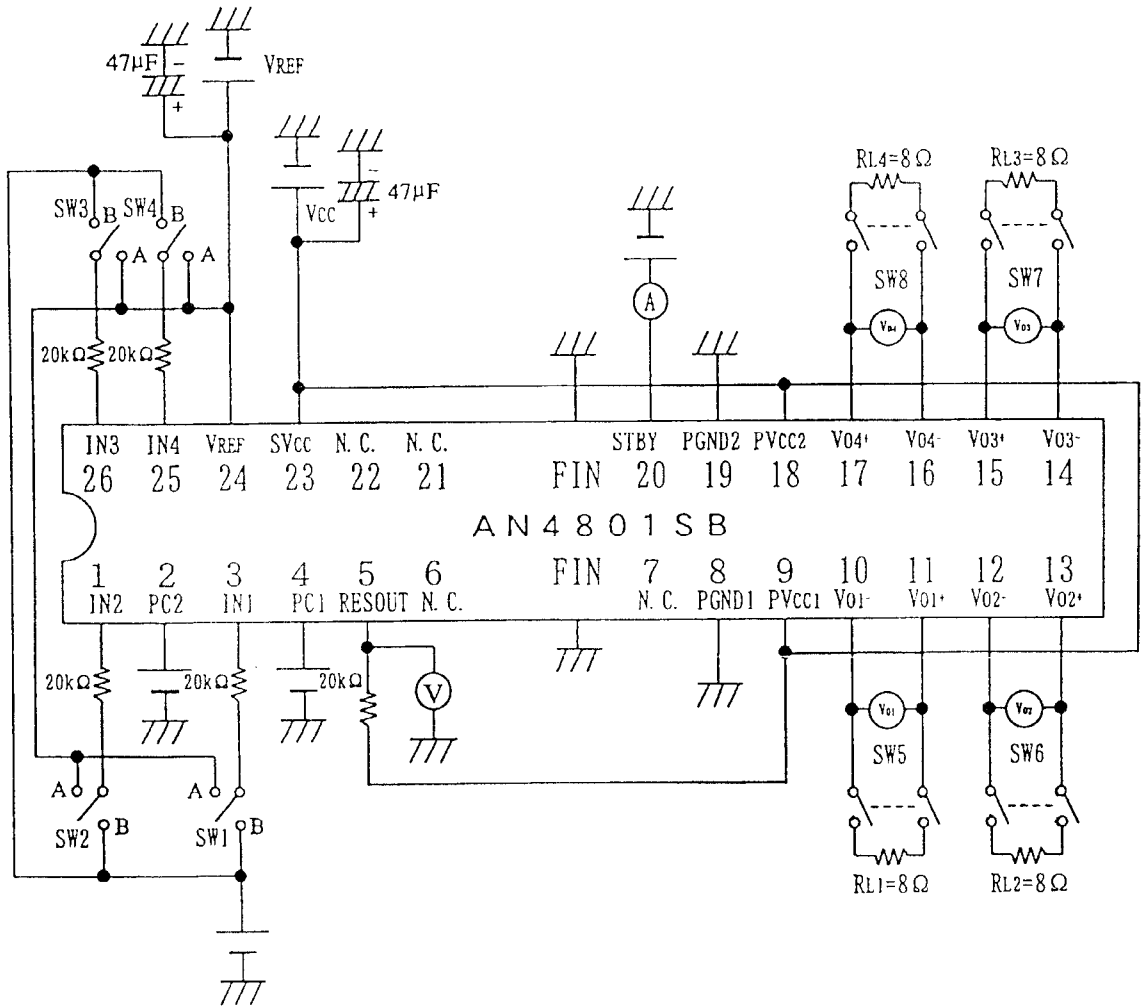
B Electrical Characteristics (Ta=25°C±2°C unless otherwise specified)									
No.	Parameter	Symbol	Test Circuit	Conditions	Limits			Unit	Note
					Min	Typ	Max		
	< Power Cut Operation >			H: Power Cut L or Hi-Z: Active					
15	High-level PC1 threshold voltage	VPC1H	1	VCC=8 V	2.2	-	-	V	
16	Low-level PC1 threshold voltage	VPC1L	1	VCC=8 V	-	-	0.7	V	
17	High-level PC2 threshold voltage	VPC2H	1	VCC=8 V	2.2	-	-	V	
18	Low-level PC2 threshold voltage	VPC2L	1	VCC=8 V	-	-	0.7	V	
19	PC1 input current	IPC1	1	VPC1=3.3 V	-	40	80	μA	
20	PC2 input current	IPC2	1	VCC2=3.3 V	-	40	80	μA	

Note) VCC=8 V, VREF=1.65 V, RL=8Ω, and VSTBY=3.3 V unless otherwise specified.

B Electrical Characteristics (Ta=25°C±2°C unless otherwise specified)									
No.	Parameter	Symbol	Test Circuit	Conditions	Limits			Unit	Note
					Min	Typ	Max		
< Thermal Shutdown Circuit >									
21	Operating temperature balancing value	TTHD	-		-	150	-	°C	
22	Operating temperature hysteresis width	ΔTTHD	-		-	45	-	°C	
23	Supply voltage detection hysteresis width	ΔVHD	-		-	0.2	-	V	

Note) Vcc=8 V, VREF=1.65 V, RL=8Ω, and VSTBY= 3.3 V unless otherwise specified.

(Description of Test Circuit and Test Method)



(Description of Test Circuit and Test Method)

### Relay Table for Test Circuit

Parameter No. \ SW	SW1	SW2	SW3	SW4	SW5	SW6	SW7	SW8
1, 2	open	open	open	open	open	open	open	open
Driver channel 1 3	A	open	open	open	on	open	open	open
Driver channel 2 3	open	A	open	open	open	on	open	open
Driver channel 3 3	open	open	A	open	open	open	on	open
Driver channel 4 3	open	open	open	A	open	open	open	on
Driver channel 1 4 to 7	B	open	open	open	on	open	open	open
Driver channel 2 4, 5, 8, 9	open	B	open	open	open	on	open	open
Driver channel 3 4, 5, 8, 9	open	open	B	open	open	open	on	open
Driver channel 4 4 to 7	open	open	open	B	open	open	open	on
10, 11	B	B	B	B	on	on	on	on
12	open	open	open	open	open	open	open	open
13, 14	B	B	B	B	on	on	on	on
15, 16	B	open	open	open	on	open	open	open
17, 18	open	B	open	open	open	on	open	open
19, 20	open	open	open	open	open	open	open	open

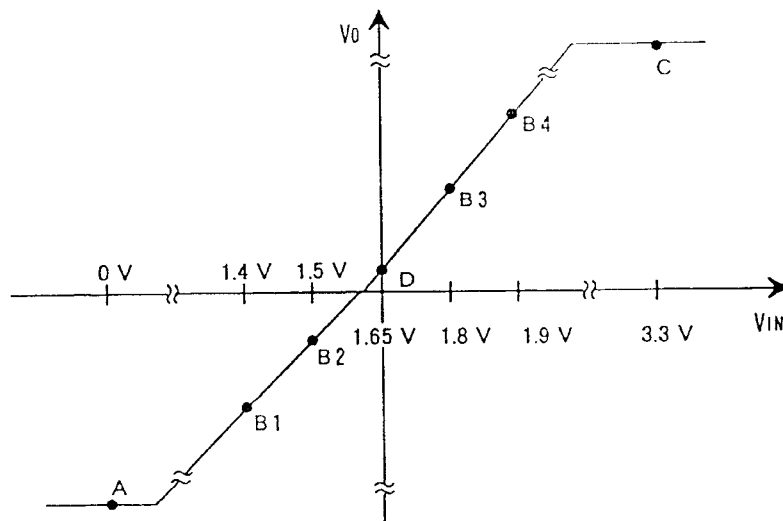


(Description of Test Circuit and Test Method)

Nos. 3 to 7 (Motor Driver)

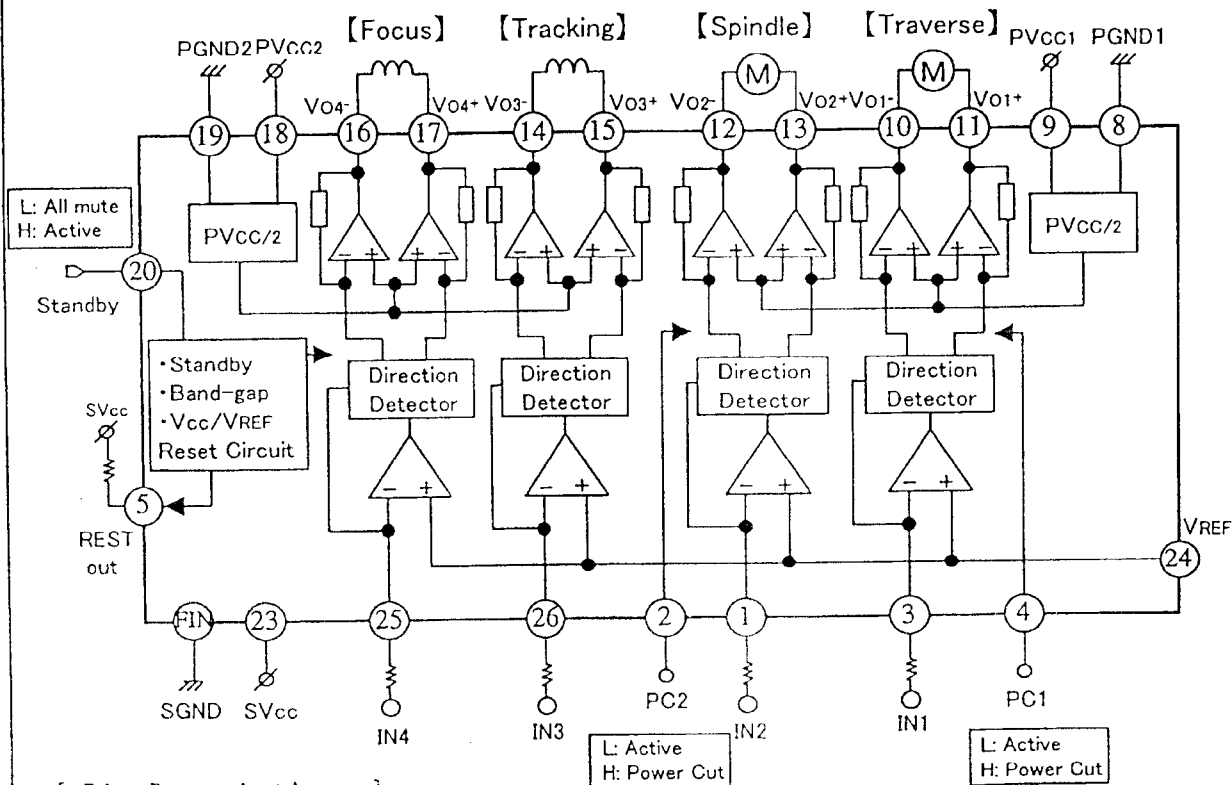
Measure the voltage difference ( $V_0$ ) between pins 10 and 11, pins 12 and 13, pins 14 and 15, or pins 16 and 17 following the description below.

No.	Parameter	Symbol	Note
3	Motor driver output offset voltage	$V_{ofs}$	Value D
4	Motor driver gain	$G+$	$20 \log_{10} \{ (B4 - B3) / 100 \text{ mV} \}$
5	Motor driver +/- relative gain	$G$	$(G+) - (G-)$ $G- = 20 \log_{10} \{ (B2 - B1) / 100 \text{ mV} \}$
6, 8	Motor driver max. output amplitude (+)	$V_{L+}$	Value C
7, 9	Motor driver max. output amplitude (-)	$V_{L-}$	Value A



C - 1 (4)	PRODUCT STANDARDS	AN4801SB		
		Total Pages	Page	10
(Description of Test Circuit and Test Method)				
<u>1. Current consumption at no load</u>				
Measure the current flowing into IC through the Vcc voltage supply pin when Vcc is set to 8 V.				
<u>2. Current consumption in standby mode</u>				
Measure the current flowing into IC through the Vcc voltage supply pin when Vcc is set to 8 V and VSTBY is set to 0 V.				
<u>10. High-level STBY threshold voltage</u>				
Check that the voltage difference Vo is 100 mV or more under the following conditions. Vcc = 8 V, VIN = VREF ± 0.05 V, VSTBY = 2.2 V				
<u>11. Low-level STBY threshold voltage</u>				
Check that the voltage difference Vo is 50 mV or less under the following conditions. Vcc = 8 V, VIN = VREF ± 0.05 V, VSTBY = 0.7 V				
<u>12. Input current in STBY (standby) mode</u>				
Measure the current flowing into IC through the STBY pin when Vcc is set to 8 V and VSTBY is set to 3.3 V.				
<u>13. Reset operation clearing supply voltage</u>				
Measure the Vcc at the moment the voltage difference Vo reaches or exceeds 100 mV while increasing the Vcc gradually from 2 V under the following condition. VIN = VREF + 0.05 V				
<u>14. VREF detecting voltage</u>				
Measure the VREF at the moment the voltage difference Vo reaches or exceeds 100 mV while increasing the VREF gradually from 0.7 V under the following condition. VIN = VREF + 0.05 V				
<u>15. High-level PCI threshold voltage</u>				
Check that the voltage difference Vo1 is 50 mV or less under the following conditions. Vcc = 8 V, VIN = VREF + 0.05 V, VPC1 = 2.2 V				
<u>16. Low-level PCI threshold voltage</u>				
Check that the voltage difference Vo1 is 100 mV or more under the following conditions. Vcc = 8 V, VIN = VREF + 0.05 V, VPC1 = 0.7 V				
<u>17. High-level PC2 threshold voltage</u>				
Check that the voltage difference Vo2 is 50 mV or less under the following conditions. Vcc = 8 V, VIN = VREF + 0.05 V, VPC2 = 2.2 V				
<u>18. Low-level PC2 threshold voltage</u>				
Check that the voltage difference Vo2 is 100 mV or more under the following conditions. Vcc = 8 V, VIN = VREF + 0.05 V, VPC2 = 0.7 V				
<u>19. PCI input current</u>				
Measure the current flowing into IC through the PCI pin when Vcc is set to 8 V and VPC1 is set to 3.3 V.				
<u>20. PC2 input current</u>				
Measure the current flowing into IC through the PC2 pin when Vcc is set to 8 V and VPC2 is set to 3.3 V.				
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[ Block Diagram ]

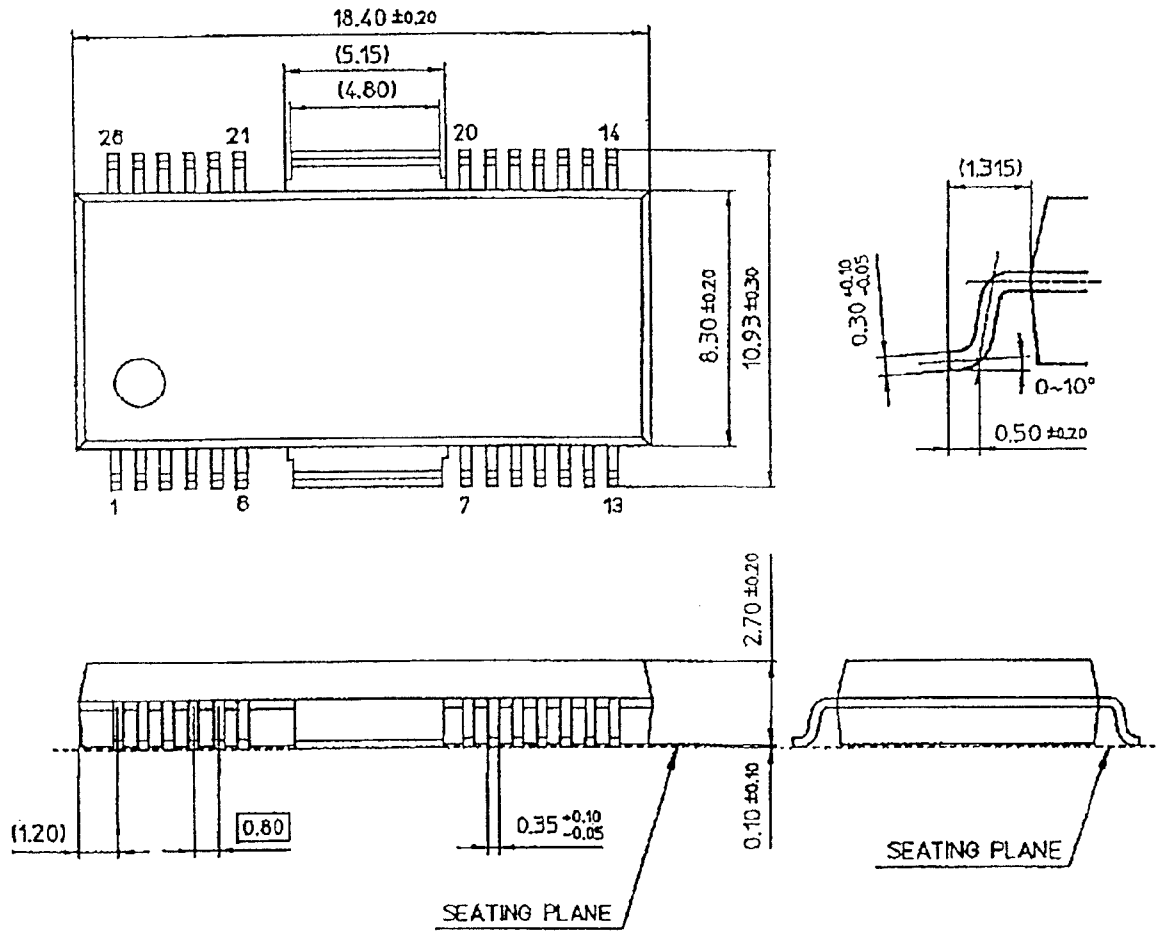


[ Pin Descriptions ]

Pin No.	Function	Pin No.	Function
1	Driver 2 input	16	Driver 4 inverted output
2	Power Cut input (Channel 2 mute)	17	Driver 4 forward output
3	Driver 1 input	18	Power supply 2 for driver
4	Power Cut input (Channel 1 mute)	19	Ground 2 for driver
5	Reset output	20	Standby input
6	N. C.	21	N. C.
7	N. C.	22	N. C.
8	Ground 1 for driver	23	Power supply
9	Power supply 1 for driver	24	VREF input
10	Driver 1 inverted output	25	Driver 4 input
11	Driver 1 forward output	26	Driver 3 input
12	Driver 2 inverted output	FIN	Ground
13	Driver 2 forward output		
14	Driver 3 inverted output		
15	Driver 3 forward output		

Package Code	IISOP042-P-0400B
Package Name	USOF-26D

Unit : mm



( ) : Reference value

Package : USOF-26D

Method : ~~Ink Marking~~ Laser Marking

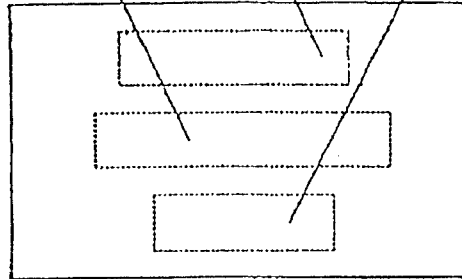
Layout : Standard

~~Special <Designated/Rank/Custom Code>~~

Type name

Logo

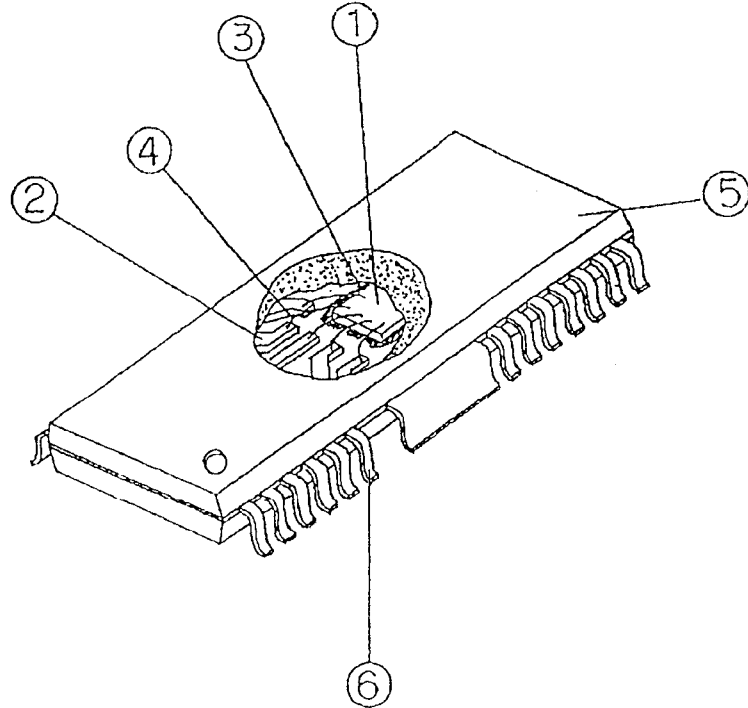
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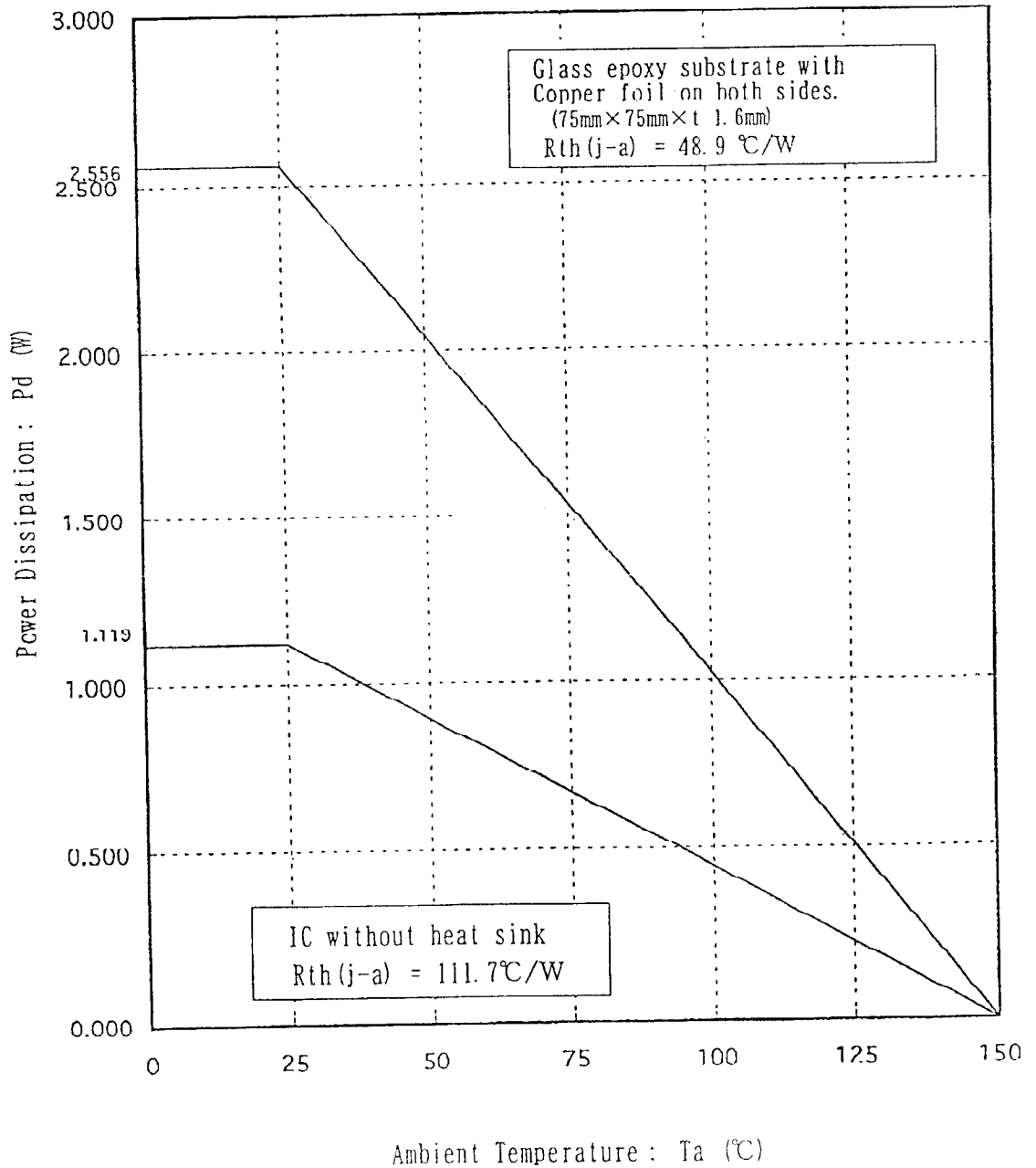
[Structure]

Chip surface passivation	SiN	①
Lead frame material	Cu group	②, ⑥
Internal lead surface treatment	Ag plating	②
External lead surface treatment	Solder dipping	⑥
Chip mounting method	Soldering	③
Wire bonding method	Thermosonic bonding	④
Wire material, diameter	Au, Diameter: 30 $\mu$ m	④
Mold material	Epoxy	⑤
Molding method	Multiplunger mold	⑤

< Package >  
USOF-26D



## USOF-26D Package Power Dissipation



H	PRODUCT STANDARDS	AN4801SB		
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<p>&lt;Precautions&gt;</p> <ul style="list-style-type: none"> <li>· Make sure that the SVCC of the IC in operation is at its maximum potential, otherwise the IC may malfunction.</li> <li>· PVCC1 and PVCC2 pins should not be used under the following conditions, <ul style="list-style-type: none"> <li>· voltage applied (3V or less)</li> <li>· high impedance state.</li> </ul> </li> <li>· None of the PVCC1 and PVCC2 can be at 3.0 V or less or in Hi-Z state while the IC is in operation.</li> <li>· Fully check the characteristics of the IC before use. The user may change the constants of the external components of the IC on condition that enough margins are provided by considering the dispersion of the transient as well as static characteristics of the IC and external components.</li> <li>· Do not short-circuit the following pins, otherwise the IC may break or give off smoke. <ul style="list-style-type: none"> <li>Output pin and VCC.</li> <li>Output pin and ground.</li> <li>Output pins together (load short-circuiting).</li> </ul> </li> <li>· Before applying solder dipping to the IC, carefully take into consideration all conditions involved.</li> </ul>				
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